Diode Semiconductor Device - Page 1 of 1



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Inclosure	Material:

Glass

Overall Length:

0.300 inches

Terminal Length:

1.000 inches

Overall Height:

0.300 inches

Overall Width:

0.107 inches

Mounting Method:

Terminal

Terminal Circle Diameter:

0.020 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

30.0 reverse breakdown voltage, dc

Current Rating Per Characteristic:

0.02 milliamperes forward current, average peak

Power Rating Per Characteristic:

400.0 milliwatts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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